

DG411/883

Monolithic Quad SPST CMOS Analog Switches

FN6726
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The DG411/883 series monolithic CMOS analog switches are drop-in replacements for the popular DG211 and DG212 series devices. They include four independent single pole throw (SPST) analog switches, and TTL and CMOS compatible digital inputs.

These switches feature lower analog ON-resistance ($<35\Omega$) and faster switch time ($t_{ON} <175ns$) compared to the DG211 or DG212. Charge injection has been reduced, simplifying sample and hold applications.

The improvements in the DG411/883 series are made possible by using a high voltage silicon-gate process. An epitaxial layer prevents the latch-up associated with older CMOS technologies. The 44V maximum voltage range permits controlling 40V_{P-P} signals. The power supplies may be single-ended from +5V to +34V, or split from $\pm 5V$ to $\pm 20V$.

The four switches are bilateral, equally matched for AC or bidirectional signals. The ON-resistance variation with analog signals is quite low over a $\pm 15V$ analog input range. This permits independent control of turn-on and turn-off times for SPDT configurations, permitting "break-before-make" or "make-before-break" operation with a minimum of external logic.

Ordering Information

PART NUMBER	TEMP. RANGE (°C)	PACKAGE	PKG. DWG. #
DG411AK/883	-55 to +125	16 Ld CerDIP	F16.3

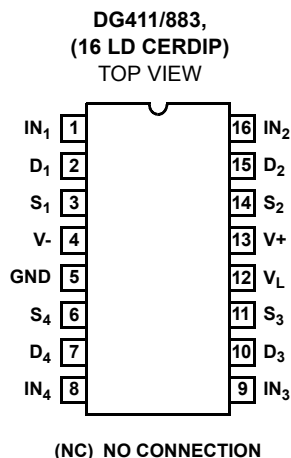
Features

- This Circuit is Processed in Accordance to MIL-STD-883 and is Fully Conformant Under the Provisions of Paragraph 1.2.1.
- ON-Resistance $<35\Omega$ Max
- Low Power Consumption ($P_D <35mW$)
- Fast Switching Action
 - $t_{ON} <175ns$
 - $t_{OFF} <145ns$
- Low Charge Injection
- Upgrade from DG211/DG212
- TTL, CMOS Compatible
- Single or Split Supply Operation

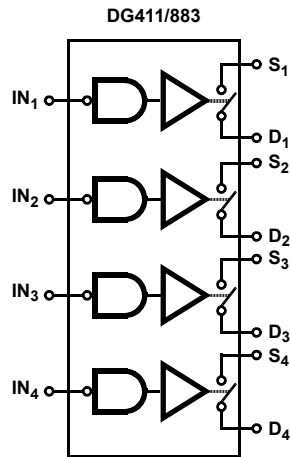
Applications

- Audio Switching
- Battery Operated Systems
- Data Acquisition
- Hi-Rel Systems
- Sample and Hold Circuits
- Communication Systems
- Automatic Test Equipment

Pinout



Functional Diagram Four SPST Switches per Package Switches Shown for Logic “1” Input



Pin Description

PIN	SYMBOL	DESCRIPTION
1	IN ₁	Logic Control for Switch 1
2	D ₁	Drain (Output) Terminal for Switch 1
3	S ₁	Source (Input) Terminal for Switch 1
4	V-	Negative Power Supply Terminal
5	GND	Ground Terminal (Logic Common)
6	S ₄	Source (Input) Terminal for Switch 4
7	D ₄	Drain (Output) Terminal for Switch 4
8	IN ₄	Logic Control for Switch 4
9	IN ₃	Logic Control for Switch 3
10	D ₃	Drain (Output) Terminal for Switch 3
11	S ₃	Source (Input) Terminal for Switch 3
12	V _L	Logic Reference Voltage
13	V+	Positive Power Supply Terminal (Substrate)
14	S ₂	Source (Input) Terminal for Switch 2
15	D ₂	Drain (Output) Terminal for Switch 2
16	IN ₂	Logic Control for Switch 2

TABLE 1. TRUTH TABLE

LOGIC	SWITCH
0	ON
1	OFF

NOTE: Logic “0” ≤0.8V. Logic “1” ≥2.4V.

Absolute Maximum Ratings

V+ to V-44V
 GND to V-25V
 V_L (Note 3)(GND -0.3V) to (V+) +0.3V
 Digital Inputs, V_S, V_D (Note 4)(V-) -2V to (V+) + 2V or 30mA,
 Whichever Occurs First
 Continuous Current (Any Terminal) 30mA
 Current, S or D (Pulsed 1ms, 10% Duty Cycle)..... 100mA

Thermal Information

Thermal Resistance (Typical, Notes 1, 2) θ_{JA} (°C/W) θ_{JC} (°C/W)
 16 Ld CERDIP Package..... 75 20
 Junction Temperature +175°C
 Operating Temperature (A Suffix)-55°C to +125°C
 Storage Temperature Range (A Suffix)-65°C to +125°C
 Lead Temperature (Soldering 10s) +300°C

Operating Conditions

Operating Voltage Range±20V Max
 Operating Temperature Range-55°C to +125°C
 Input Low Voltage 0.8V Max
 Input High Voltage2.4V Min
 Input Rise and Fall Time≤20ns

CAUTION: Do not operate at or near the maximum ratings listed for extended periods of time. Exposure to such conditions may adversely impact product reliability and result in failures not covered by warranty.

NOTES:

1. θ_{JA} is measured in free air with the component mounted on a high effective thermal conductivity test board with "direct attach" features. See Tech Brief [TB379](#).
2. For θ_{JC} , the "case temp" location is the center of the ceramic on the package underside
3. V_{IN} = Input Voltage to Perform Proper Function.
4. Signals on S_X, D_X or IN_X exceeding V+ or V- will be clamped by internal diodes. Limit forward diode current to maximum current ratings.

DC Electrical Specifications Device Tested at: V+ = +15V, V- = -15V, V_L = 5V, GND = 0V, Unless Otherwise Specified.

PARAMETERS	SYMBOL	CONDITIONS	GROUP A SUBGROUP	TEMPERATURE (°C)	LIMITS		UNITS
					MIN (Note 5)	MAX (Note 5)	
Drain-to-Source ON-Resistance	$r_{DS(ON)}$	V+ = +13.5V, V- = -13.5V, I _S = -10mA, V _D = ±8.5V V _{IN} = 0.8V	1, 3	+25, -55	0	35	Ω
			2	+125	0	45	Ω
		V+ = +10.8V, V- = -0V, I _S = -10mA, V _D = 3.0V and 8.0V V _{IN} = 0.8V	1, 3	+25, -55	0	80	Ω
			2	+125	0	100	Ω
Source OFF Leakage Current	$I_{S(OFF)}$	V+ = 16.5V, V- = -16.5V, V _D = -15.5V, V _S = 15.5V V _{IN} = 2.4V	1	+25	-0.25	+0.25	nA
			2, 3	+125, -55	-20	+20	nA
		V+ = 16.5V, V- = -16.5V, V _D = 15.5V, V _S = -15.5V V _{IN} = 2.4V	1	+25	-0.25	+0.25	nA
			2, 3	+125, -55	-20	+20	nA
Drain OFF Leakage Current	$I_{D(OFF)}$	V+ = 16.5V, V- = -16.5V, V _D = -15.5V, V _S = 15.5V V _{IN} = 2.4V	1	+25	-0.25	+0.25	nA
			2, 3	+125, -55	-20	+20	nA
		V+ = 16.5V, V- = -16.5V, V _D = 15.5V, V _S = -15.5V V _{IN} = 2.4V	1	+25	-0.25	+0.25	nA
			2, 3	+125, -55	-20	+20	nA

DC Electrical Specifications Device Tested at: V+ = +15V, V- = -15V, VL = 5V, GND = 0V, Unless Otherwise Specified. (Continued)

PARAMETERS	SYMBOL	CONDITIONS	GROUP A SUBGROUP	TEMPERATURE (°C)	LIMITS		UNITS
					MIN (Note 5)	MAX (Note 5)	
Channel ON Leakage Current	ID(ON) + IS(ON)	V+ = 16.5V, V- = -16.5V, VS = VD = ±15.5V	1	+25	-0.4	+0.4	nA
			2, 3	+125, -55	-40	+40	nA
Input Current with VIN Low	IIL	Input Under Test = 0.8V, All Others = 2.4V	1, 2, 3	+25, +125, -55	-0.5	+0.5	µA
Input Current with VIN High	IiH	Input Under Test = 2.4V, All Others = 0.8V	1, 2, 3	+25, +125, -55	-0.5	+0.5	µA
Positive Supply Current	I+	V+ = 16.5V, V- = -16.5, VIN = 0V or 5.0V	1	+25	-	+1.0	µA
			2, 3	+125, -55	-	+5.0	µA
		V+ = 13.2V, V- = 0V, VIN = 0V or 5.0V VL = 5.25V	1	+25	-	+1.0	µA
			2, 3	+125, -55	-	+5.0	µA
Negative Supply Current	I-	V+ = 16.5V, V- = -16.5, VIN = 0V or 5.0V	1	+25	-1.0	-	µA
			2, 3	+125, -55	-5.0	-	µA
		V+ = 13.2V, V- = 0V, VIN = 0V or 5.0V VL = 5.25V	1	+25	-1.0	-	µA
			2, 3	+125, -55	-5.0	-	µA
Logic Supply Current	IL	V+ = 16.5V, V- = -16.5, VIN = 0V or 5.0V	1	+25	-	+1.0	µA
			2, 3	+125, -55	-	+5.0	µA
		V+ = 13.2V, V- = 0V, VIN = 0V or 5.0V VL = 5.25V	1	+25	-	+1.0	µA
			2, 3	+125, -55	-	+5.0	µA
Ground Current	IGND	V+ = 16.5V, V- = -16.5, VIN = 0V or 5.0V	1	+25	-1.0	-	µA
			2, 3	+125, -55	-5.0	-	µA
		V+ = 13.2V, V- = 0V, VIN = 0V or 5.0V VL = 5.25V	1	+25	-1.0	-	µA
			2, 3	+125, -55	-5.0	-	µA

AC Electrical Specifications Device Tested at: V+ = +15V, V- = -15V, VL = 5V, GND = 0V, Unless Otherwise Specified.

PARAMETERS	SYMBOL	CONDITIONS	GROUP A SUBGROUP	TEMPERATURE (°C)	LIMITS		UNITS
					MIN (Note 5)	MAX (Note 5)	
Turn ON Time	tON	CL = 35pF, VS = ±10V, RL = 300Ω	9, 11	+25, -55	0	175	ns
			10	+125	0	240	ns
		V+ = 12V, V- = 0V, CL = 35pF, VS = +8V, RL = 300Ω	9, 11	+25, -55	0	250	ns
			10	+125	0	400	ns
Turn OFF Time	tOFF	CL = 35pF, VS = ±10V, RL = 300Ω	9, 11	+25, -55	0	145	ns
			10	+125	0	160	ns
		V+ = 12V, V- = 0V, CL = 35pF, VS = +8V, RL = 300Ω	9, 11	+25, -55	0	125	ns
			10	+125	0	140	ns

Electrical Specifications Device Tested at: $V_+ = +15V$, $V_- = -15V$, $V_L = 5V$, $GND = 0V$, Unless Otherwise Specified.

PARAMETERS	SYMBOL	CONDITIONS	GROUP A SUBGROUP	TEMPERATURE (°C)	LIMITS		UNITS
					MIN (Note 5)	MAX (Note 5)	
Charge Injection	Q	$V_G = 0V$, $R_G = 0\Omega$, $T_A = +25^\circ C$, $C_L = 10nF$ (see Figure 2)	9	+25	-100	+100	pC
				+25			pC
		$V_G = 6V$, $R_G = 0\Omega$, $T_A = +25^\circ C$, $C_L = 10nF$, $V_+ = 12V$, $V_- = 0V$ (see Figure 2)	9	+25	-100	+100	pC
				+25			pC

NOTE:

- 5. Parameters with MIN and/or MAX limits are 100% tested at +25°C, unless otherwise specified. Temperature limits established by characterization and are production tested.

TABLE 2. ELECTRICAL TEST REQUIREMENTS

MIL-STD-883 TEST REQUIREMENTS	SUBGROUPS (See "Electrical Spec Tables" on page 3 and page 4)
Interim Electrical Parameters (Pre Burn-In)	1
Final Electrical Test Parameters	1 (Note 6), 2, 3, 9, 10, 11
Group A Test Requirements	1, 2, 3, 9, 10, 11
Groups C and D Endpoints	1

NOTE:

- 6. PDA applies to Subgroup 1 only.

Typical Performance Curves

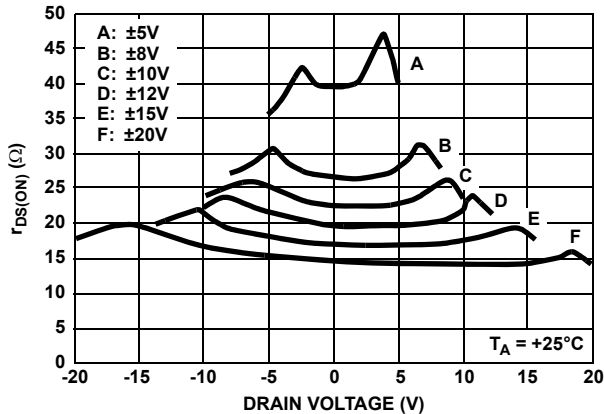


FIGURE 1. ON-RESISTANCE vs V_D AND POWER SUPPLY VOLTAGE

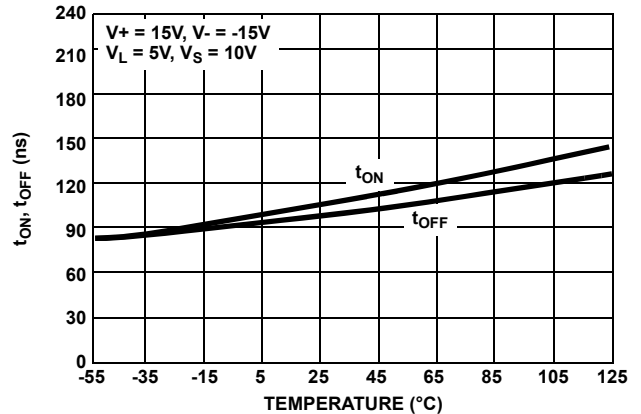


FIGURE 2. SWITCHING TIME vs TEMPERATURE

Typical Performance Curves (Continued)

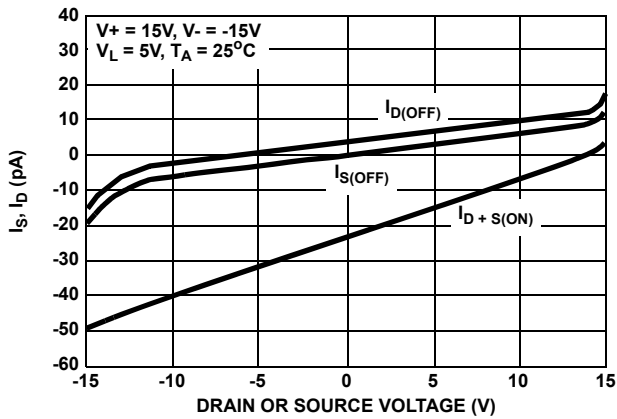


FIGURE 3. LEAKAGE CURRENT vs ANALOG VOLTAGE

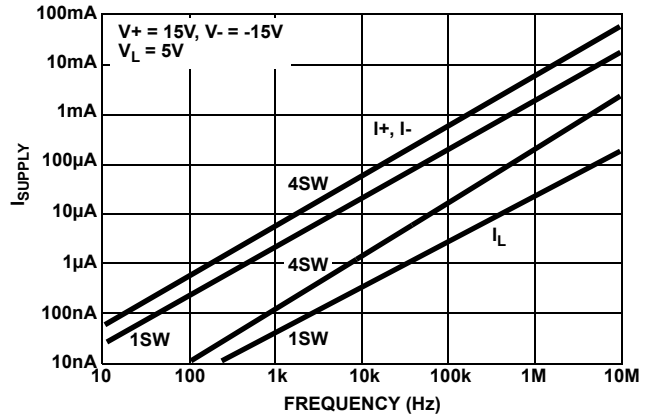


FIGURE 4. SUPPLY CURRENT vs INPUT SWITCHING FREQUENCY

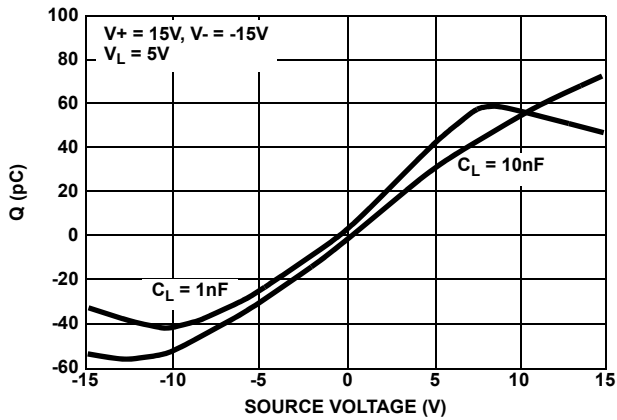


FIGURE 5. CHARGE INJECTION vs ANALOG VOLTAGE (V_D)

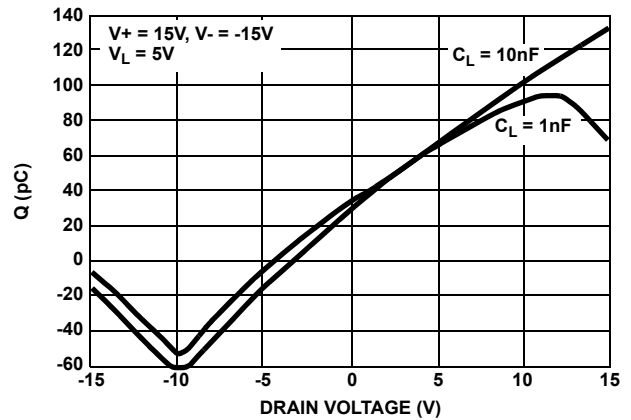
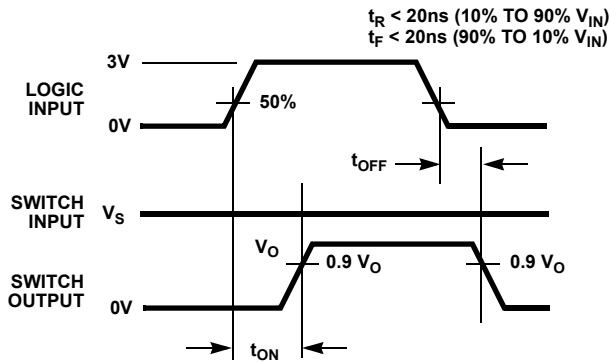


FIGURE 6. CHARGE INJECTION vs ANALOG VOLTAGE (V_S)

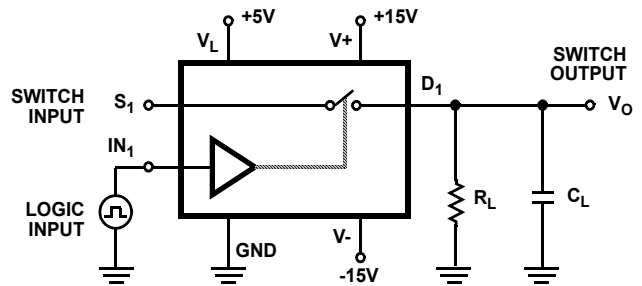
Test Circuits

V_O is the steady state output with the switch on. Feedthrough via switch capacitance may result in spikes at the leading and trailing edge of the output waveform



NOTE: Logic input waveform is inverted for switches that have the opposite logic sense.

FIGURE 7A.



Repeat test for all IN and S.
For load conditions, see Specifications C_L (includes fixture and stray capacitance)

$$V_O = V_S \frac{R_L}{R_L + r_{DS(ON)}}$$

FIGURE 7B.

FIGURE 7. SWITCHING TIME

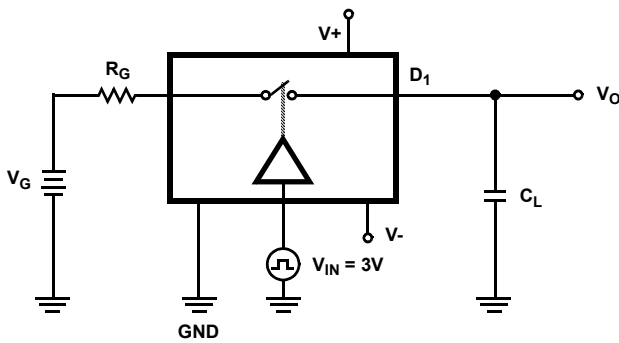
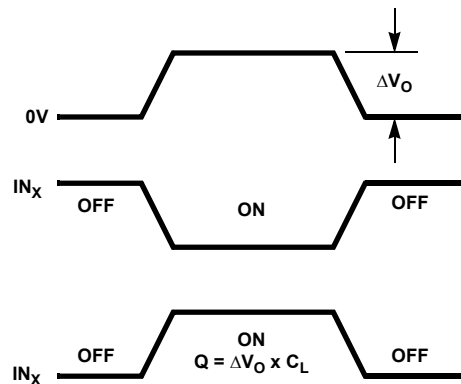


FIGURE 8A.

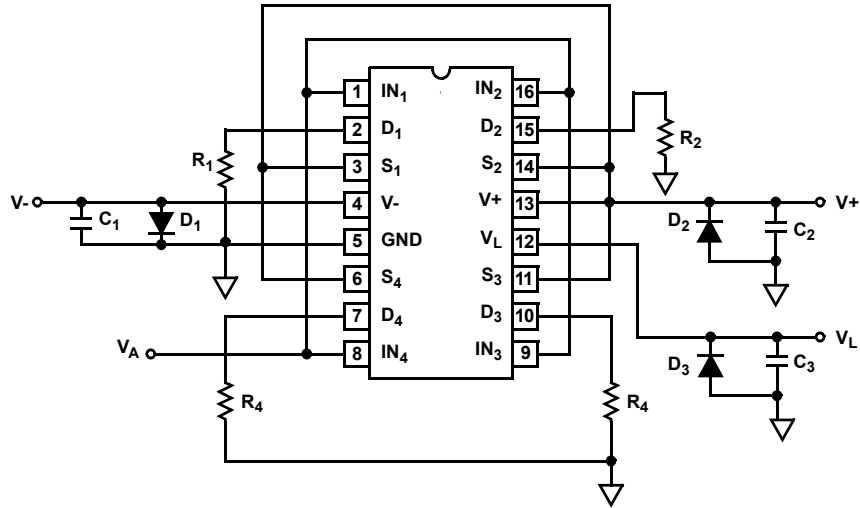


IN_X dependent on switch configuration input polarity determined by sense of switch.

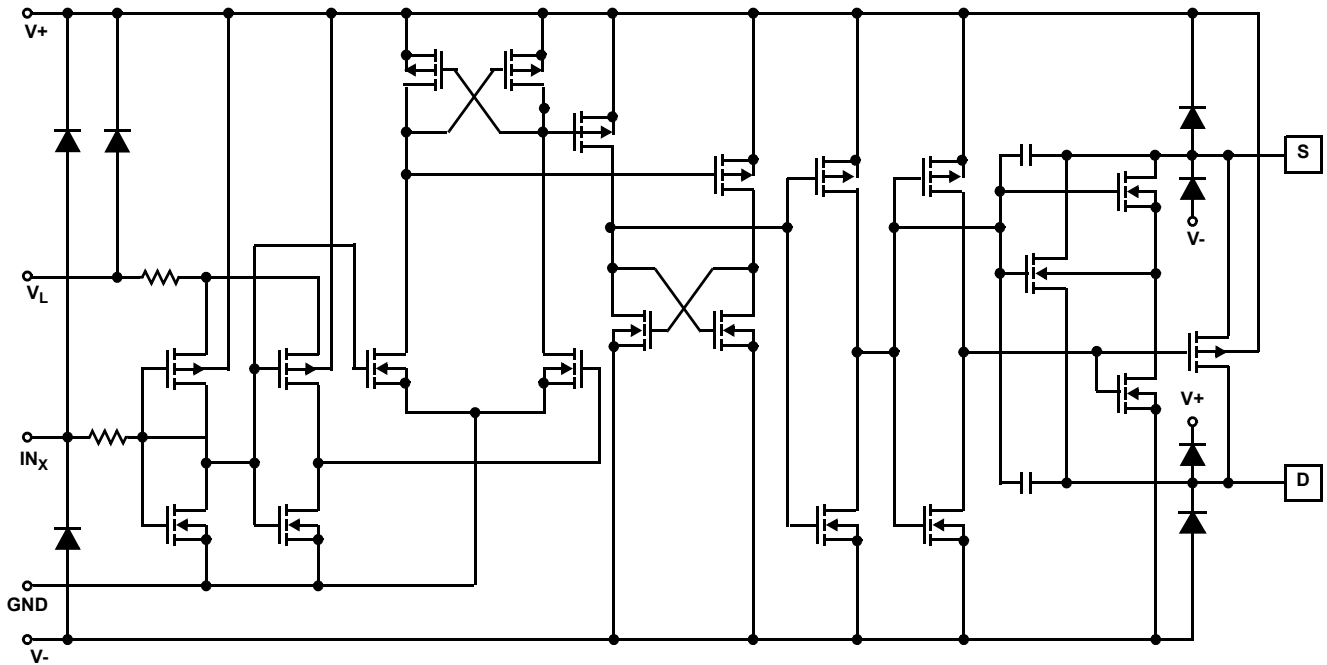
FIGURE 8B.

FIGURE 8. CHARGE INJECTION

Burn-In Circuit



Typical Schematic Diagram (Typical Channel)



Die Characteristics

WORST CASE CURRENT DENSITY:
 $1.5 \times 10^5 \text{A/cm}^2$

DIE DIMENSIONS:

2760 μm x 1780 μm x 485 \pm 25 μm

METALLIZATION:

Type: SiAl

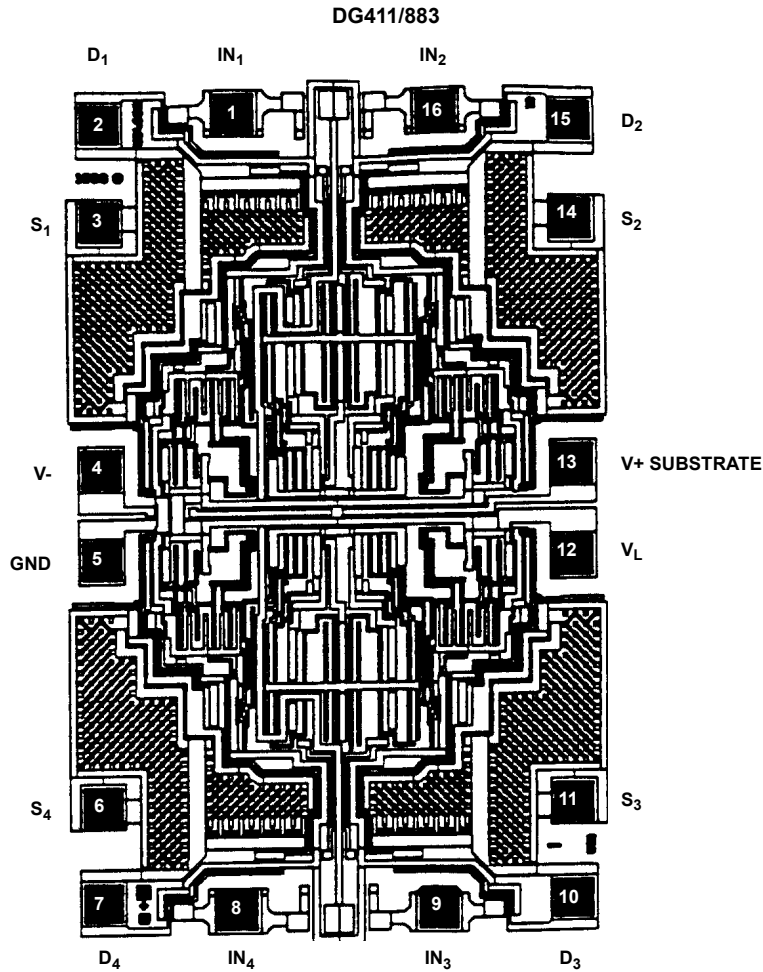
Thickness: 12k \AA \pm 1k \AA

GLASSIVATION:

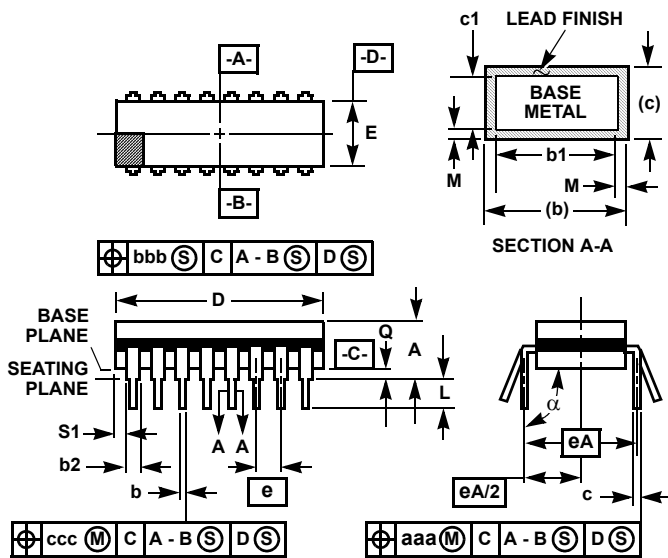
Type: Nitride

Thickness: 8k \AA \pm 1k \AA

Metallization Mask Layout



Ceramic Dual-In-Line Frit Seal Packages (CERDIP)



NOTES:

1. Index area: A notch or a pin one identification mark shall be located adjacent to pin one and shall be located within the shaded area shown. The manufacturer's identification shall not be used as a pin one identification mark.
2. The maximum limits of lead dimensions b and c or M shall be measured at the centroid of the finished lead surfaces, when solder dip or tin plate lead finish is applied.
3. Dimensions b1 and c1 apply to lead base metal only. Dimension M applies to lead plating and finish thickness.
4. Corner leads (1, N, N/2, and N/2+1) may be configured with a partial lead paddle. For this configuration dimension b3 replaces dimension b2.
5. This dimension allows for off-center lid, meniscus, and glass overrun.
6. Dimension Q shall be measured from the seating plane to the base plane.
7. Measure dimension S1 at all four corners.
8. N is the maximum number of terminal positions.
9. Dimensioning and tolerancing per ANSI Y14.5M - 1982.
10. Controlling dimension: INCH.

**F16.3 MIL-STD-1835 GDIP1-T16 (D-2, CONFIGURATION A)
16 LEAD CERAMIC DUAL-IN-LINE FRIT SEAL PACKAGE**

SYMBOL	INCHES		MILLIMETERS		NOTES
	MIN	MAX	MIN	MAX	
A	-	0.200	-	5.08	-
b	0.014	0.026	0.36	0.66	2
b1	0.014	0.023	0.36	0.58	3
b2	0.045	0.065	1.14	1.65	-
b3	0.023	0.045	0.58	1.14	4
c	0.008	0.018	0.20	0.46	2
c1	0.008	0.015	0.20	0.38	3
D	-	0.840	-	21.34	5
E	0.220	0.310	5.59	7.87	5
e	0.100 BSC		2.54 BSC		-
eA	0.300 BSC		7.62 BSC		-
eA/2	0.150 BSC		3.81 BSC		-
L	0.125	0.200	3.18	5.08	-
Q	0.015	0.060	0.38	1.52	6
S1	0.005	-	0.13	-	7
α	90°	105°	90°	105°	-
aaa	-	0.015	-	0.38	-
bbb	-	0.030	-	0.76	-
ccc	-	0.010	-	0.25	-
M	-	0.0015	-	0.038	2, 3
N	16		16		8

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